

Form PTO 1449 U.S. Department of Commerce Patent and Trademark Office Information Disclosure Statement by Applicant	ATTY. DOCKET NUMBER HITA-0414	SERIAL NUMBER To be assigned
	APPLICANT Sato et al.	
	FILING DATE Concurrently herewith	GROUP

U.S. Patent Documents

Examiner Initial	Cited by Examiner in Parent	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE
HM	X	6,343,163	1/29/2002	Kawanishi	385	2	3/16/2000
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Foreign Patent Documents

Examiner Initial	DOCUMENT NUMBER	FILING DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION	
						YES	NO

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

HM	AA	Seung Won Lee, Jeong Soo Kim, Eun Soo Nam, Chan Yong Park, Chong Dae Park, Hong Man Kim and Kwang Eui Pyun, "Growth of Defect-free Butt-coupled InGaAsP/InGaAsP Strain Compensated Multiple Quantum Well by Metal-Organic Vapor Phase Epitaxy," Optoelectronics Section, Electronics and Telecommunications Research Institute Yusong, pp. 189-190. (May 2001)

EXAMINER Mai	DATE CONSIDERED 5/20/04
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EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP 609; draw a line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant